

CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)

Applicant(s): KANGGUO CHENG ET AL.

Docket No.

FIS920030163US1

Serial No.
10/604,565Filing Date
07/30/2003Examiner
THAO P. LEGroup Art Unit
2818

Invention: METHOD AND STRUCTURE FOR VERTICAL DRAM DEVICES WITH SELF-ALIGNED UPPER TRENCH SHAPING

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I hereby certify that this Response to Restriction Requirement
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: KANGGUO CHENG ET AL.)
Serial No.: 10/604,565) Group Art Unit: 2818
Filed: July 30, 2003)
For: METHOD AND STRUCTURE FOR) Examiner:
 VERTICAL DRAM DEVICES WITH) THAO P. LE
 SELF-ALIGNED UPPER TRENCH) Confirmation No.: 1564
 SHAPING)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO RESTRICTION REQUIREMENT

In response to the restriction requirement mailed on April 26, 2004, and in accordance with the provisions under 37 CFR § 1.115 and 1.143, the Applicants submit the following election for further prosecution on the merits:

I25-0014
FIS920030163US1

Election:

Applicants hereby elect, without traverse, Group I, claims 1-20, drawn to a method of fabricating a memory storage cell, classified in class 438, subclass 257.

125-0014
FIS920030163WS1